



Advanced
Micro
Devices

Am26LS34

Quad Differential Line Receiver

DISTINCTIVE CHARACTERISTICS

- Meets all requirements of EIA Standards RS-442, RS-423, CCITT V.10 and V.11, and the new party line standard in development under EIA Project Number 1360.
- ± 200 mV sensitivity over input voltage range.
- ± 150 mV sensitivity for $V_{CM} = 0$.
- -7 V to $+12$ V common mode input voltage range.
- 12 k Ω minimum input impedance.
- Maximum guarantees for t_{PD} skew.
- All AC and DC parameters guaranteed over military and commercial temperature ranges.
- Guaranteed input voltages hysteresis limits.
 - 120mV minimum
 - 300mV maximum
- No internal failsafe.
- Pin compatible with Am26LS32/32B/33

GENERAL DESCRIPTION

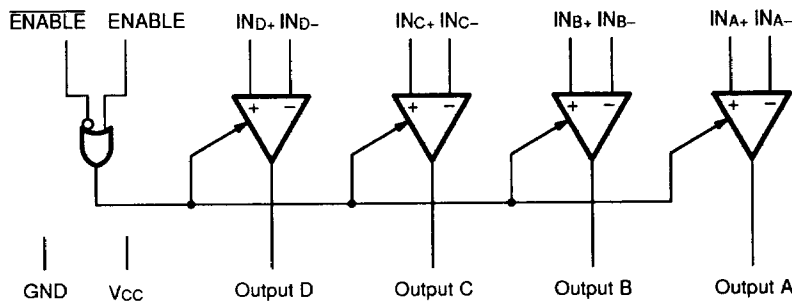
The Am26LS34 is a high performance, quad, differential line receiver. It has higher impedance and higher input voltage hysteresis than the similar Am26LS32B. The Am26LS34 also does not have internal fail-safe to allow greater user flexibility.

Input threshold sensitivity is specified for three different V_{CM} ranges. The improved sensitivity, guaranteed hys-

teresis and skew limits allow a more critical analysis of system performance in high noise environments and better system performance capability.

All performance parameters are guaranteed over $\pm 10\%$ supplies and over the operating temperature range. In addition; I_{OL} is specified to 24 mA for easy system bus interfacing.

BLOCK DIAGRAM



01025-001A

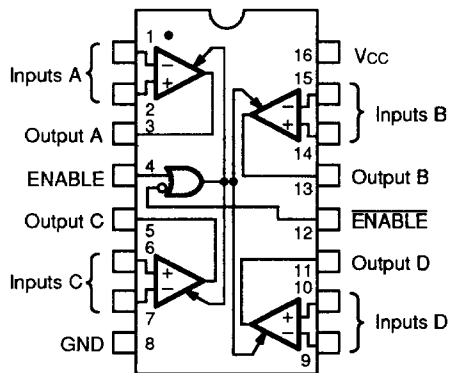
RELATED PRODUCTS

Part Number	Description
26LS29	Quad Three-State Single Ended RS-423 Line Driver
26LS30	Dual Differential RS-422 Party Line/Quad Single Ended RS-423 Line Driver
26LS32	Quad Differential Line Receiver
26LS33	Quad Differential Line Receiver

CONNECTION DIAGRAMS

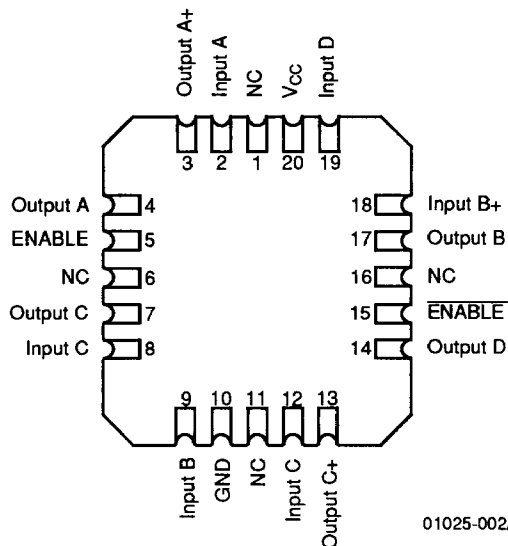
Top View

DIP



01025-003A

LCC



01025-002A

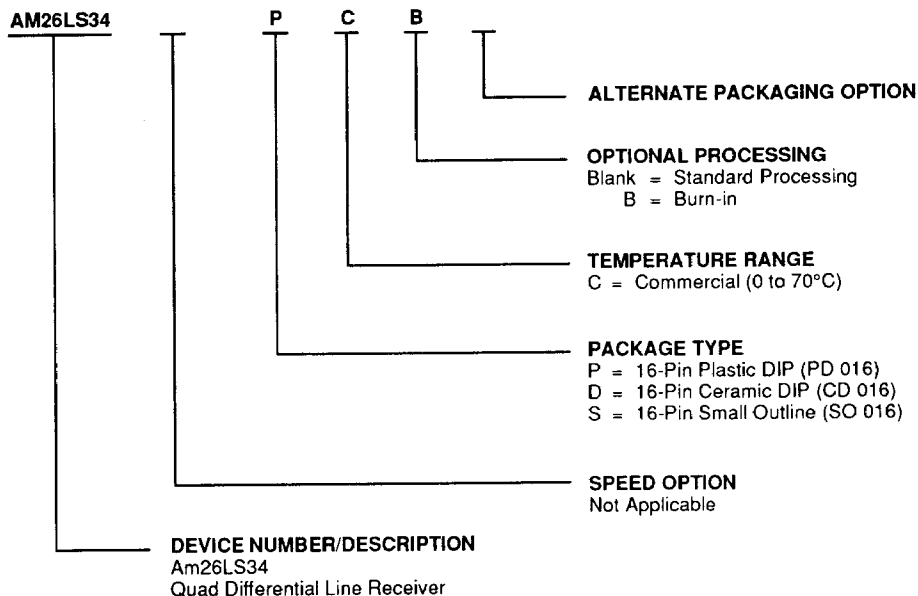
Note:

Pin 1 is marked for orientation

ORDERING INFORMATION

Standard Products

AMD products are available in several packages and operating ranges. The ordering number (Valid Combination) is formed by a combination of:



AM26LS34	PC, PCB, DC, DCB, SC
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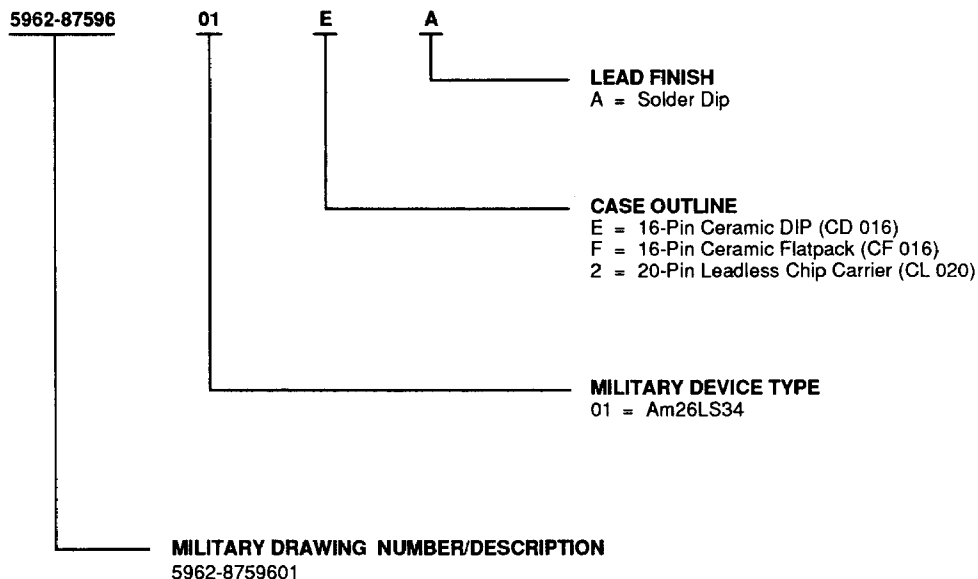
Valid Combinations

The Valid Combinations table lists configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations, to check on newly released combinations, and to obtain additional data on AMD's standard military grade products.

ORDERING INFORMATION

Standard Military Drawing Products

AMD products for Aerospace and Defense applications are available in several packages and operating ranges. Standard Military Drawing (SMD)/DESC products are fully compliant with MIL-STD-883C requirements. The ordering number for SMD/DESC (Valid Combination) is formed by a combination of:



5962-8759601	EA, FA, 2A
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Valid Combinations

The Valid Combinations table lists configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations, to check on newly released combinations, and to obtain additional data on AMD's standard military grade products.

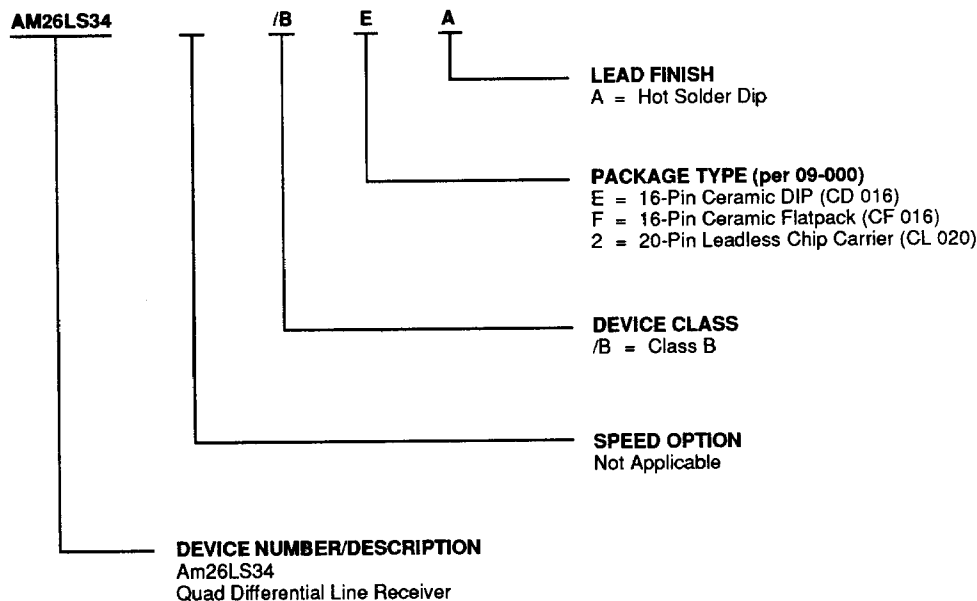
Group A Tests

Group A tests consist of Subgroups 1, 2, 3, 7, 8, 9, 10, 11.

ORDERING INFORMATION

APL Products

AMD products for Aerospace and Defense applications are available in several packages and operating ranges. APL (Approved Products List) products are fully compliant with MIL-STD-883C requirements. The ordering number (Valid Combination) is formed by a combination of:



AM26LS34	/BEA, /BFA, /B2A
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Valid Combinations

The Valid Combinations table lists configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations, to check on newly released combinations, and to obtain additional data on AMD's standard military grade products.

Group A Tests

Group A tests consist of Subgroups 1, 2, 3, 7, 8, 9, 10, 11.

ABSOLUTE MAXIMUM RATINGS

Supply Voltage	7.0 V
Common Mode Voltage	± 25 V
Differential Input Voltage	± 30 V
Enable Voltage	7.0 V
Output Sink Current	50mA
Storage Temperature Range	-65°C to $+165^{\circ}\text{C}$

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to absolute maximum ratings for extended periods may affect device reliability.

OPERATING RANGES**Commercial (C) Devices**

Temperature (T_A)	0°C to $+70^{\circ}\text{C}$
Supply Voltage (V_{CC})	$+4.75$ V to $+5.25$ V

Military (M) Devices

Temperature (T_A)	-55 to $+125^{\circ}\text{C}$
Supply Voltage (V_{CC})	$+4.5$ V to $+5.5$ V

Operating ranges define those limits between which the functionality of the device is guaranteed.

DC CHARACTERISTICS over COMMERCIAL operating range unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions		Min.	Typ.	Max.	Unit
V _{TH}	Differential Input Voltage	V _{OUT} = V _{OL} or V _{OH} (Note 5)	0V < V _{CM} < + 5 V	-100	±90	+100	mV
			-7V ≤ V _{CM} ≤ +12 V	-200		+200	
			-15V ≤ V _{CM} ≤ +15 V	-400		+400	
V _{HYST}	Input Hysteresis	V _{CC} = 5.0 V		120	180	300	mV
R _{IN}	Input Resistance	-15 V ≤ V _{CM} ≤ + 15 V (One input AC ground) (Note 4)		12k	20k	40k	Ω
I _{IN}	Input Current (Under Test)	V _{IN} = +12 V			0.7	1.0	mA
I _{IN}	Input Current (Under Test)	V _{IN} = -7 V			-0.5	-0.8	mA
V _{OH}	Output HIGH Voltage	V _{CC} = Min., Δ V _{IN} = +1.0 V V _{ENABLE} = 0.8 V	-12 mA	2.0			V
			-1 mA	2.4		3.4	
V _{OL}	Output LOW Voltage	V _{CC} = Min., Δ V _{IN} = -1.0 V V _{ENABLE} = 0.8 V	I _{OH} = 16 mA			0.4	V
			I _{OL} = 24 mA			0.5	
V _{IL}	Enable LOW Voltage	(Note 2)				0.8	V
V _{IH}	Enable HIGH Voltage	(Note 2)		2.0			V
V _I	Enable CLAMP Voltage	V _{CC} = Min., I _{IN} = -18 mA				-1.5	V
V _{IOC}	Open Circuit Input Voltage			2.0		3.0	V
I _O	Off-State (High impedance) Output Current	V _{CC} = Max.	V _O = 2.4 V			50	μA
			V _O = 0.4 V			-50	
I _{IL}	Enable LOW Current	V _{IN} = 0.4 V			-0.03	-0.2	mA
I _{IH}	Enable HIGH Current	V _{IH} = 2.7 V			0.5	20	μA
I _I	Enable Input High Current	V _{IN} = 5.5 V			1	100	μA
I _{SC}	Output Short Circuit Current	V _O = 0 V, V _{CC} = Max., Δ V _{IN} = +1.0 V (Note 3)		-30	-65	-120	mA
I _{CC}	Power Supply Current	V _{CC} = Max., All V _{IN} = GND, Outputs Disabled			52	70	mA

Notes:

1. All typical values are $V_{CC} = 5.0\text{V}$, $T_A = 25^{\circ}\text{C}$.
2. Input thresholds are tested during DC tests and may be done in combination with testing of other DC parameters.
3. Not more than one output should be shorted at a time. Duration of short circuit test should not exceed one second.
4. R_{IN} is not directly tested but is correlated. (See Attachment I)
5. Input voltage is not tested directly due to tester accuracy limitations but is tester correlated. (See Attachment II)

SWITCHING CHARACTERISTICS over operating ranges unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions	Commercial		Military		Units
			Am26LS34		Am26LS34		
			Min.	Max.	Min.	Max.	
t _{PLH}	Propagation Delay, Input to Output	C _L = 50 pF See test circuit		30		30	ns
t _{PHL}				30		30	ns
t _{SKEW}	Propagation Delay Skew, t _{PLH} – t _{PHL}			±5		±5	ns
t _{ZL}	Output Enable Time, ENABLE to Output			33		33	ns
t _{ZH}				22		22	ns
t _{LZ}	Output Disable Time, ENABLE to Output	C _L = 5 pF See test circuit		27		27	ns
t _{LH}				27		27	ns

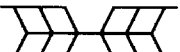
SWITCHING CHARACTERISTICS (T_A = +25°C, V_{CC} = 5.0 V)

Parameter Symbol	Parameter Description	Test Conditions	Min.	Typ.	Max.	Unit
t _{PLH}	Propagation Delay, Input to Output	C _L = 50 pF See test circuit		18	24	ns
t _{PHL}				20	24	ns
t _{SKEW}	Propagation Delay Skew, t _{PLH} – t _{PHL}					
				2	4	ns
t _{ZL}	Output Enable Time, ENABLE to Output			16	22	ns
t _{ZH}			10	16	ns	
t _{lZ}	Output Disable Time, ENABLE to Output	C _L = 5 pF See test circuit		11	18	ns
t _{lH}				13	18	ns

Tristate Delays For Enable Bar

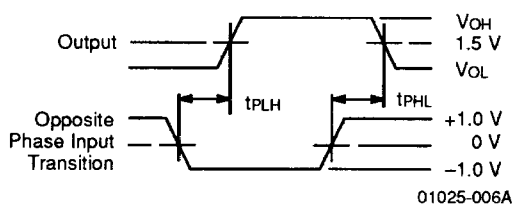
Parameter Symbol	Parameter Description	Test Conditions	Min.	Typ.	Max.	Unit
t _{PZH}	Propagation Delay From ENABLE BAR to Output	C _L = 50 pF, R _{L1} = 1 KΩ, R _{L2} = 280 Ω			26	ns
t _{PZL}	Propagation Delay From ENABLE BAR to Output	C _L = 50 pF, R _{L1} = 1 KΩ, R _{L2} = 280 Ω			33	ns
t _{PHZ}	Propagation Delay From ENABLE BAR to Output	C _L = 5 pF, R _{L1} = 1 KΩ, R _{L2} = 280 Ω			20	ns
t _{PLZ}	Propagation Delay From ENABLE BAR to Output	C _L = 5 pF, R _{L1} = 1 KΩ, R _{L2} = 280 Ω			20	ns
t _{PZH}	Propagation Delay From ENABLE BAR to Output	C _L = 50 pF, R _{L1} = 1 KΩ, R _{L2} = 280 Ω			39	ns
t _{PZL}	Propagation Delay From ENABLE BAR to Output	C _L = 50 pF, R _{L1} = 1 KΩ, R _{L2} = 280 Ω			49	ns
t _{PHZ}	Propagation Delay From ENABLE BAR to Output	C _L = 5 pF, R _{L1} = 1 KΩ, R _{L2} = 280 Ω			30	ns
t _{PLZ}	Propagation Delay From ENABLE BAR to Output	C _L = 5 pF, R _{L1} = 1 KΩ, R _{L2} = 280 Ω			30	ns

KEY TO SWITCHING WAVEFORMS

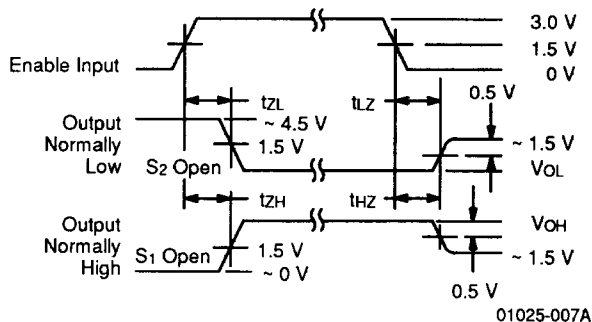
WAVEFORM	INPUTS	OUTPUTS
	Must Be Steady	Will Be Steady
	May Change from H to L	Will Be Changing from H to L
	May Change from L to H	Will Be Changing from L to H
	Don't Care, Any Change Permitted	Changing State Unknown
	Does Not Apply	Center Line is High Impedance "Off" State

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SWITCHING WAVEFORMS



Propagation Delay
(Notes 1 and 3)

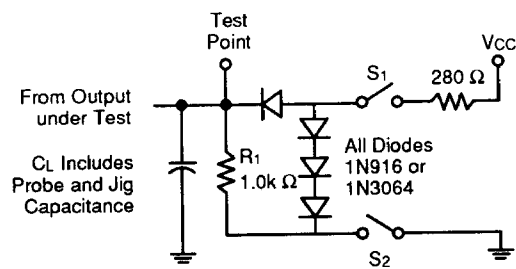


Enable And Disable Times
(Notes 2 and 3)

Notes:

1. Diagram shown for ENABLE LOW.
2. S₁ and S₂ of Load Circuit are closed except where shown.
3. Pulse Generator Rate ≤ 1.0 MHz; Z₀ = 50Ω; t_r; t_f ≤ 2.5ns.

SWITCHING TEST CIRCUIT



01025-005A

Three-State Outputs

ATTACHMENT I**Am26LS32/32B/33/34 Input Resistance and Input Current**

Input resistance measurement for differential inputs on line receivers are generally not measured directly. Instead they are correlated to an input current measurement and to the process resistor temperature coefficient. The assumptions made include 1) Process resistor temperature coefficient is known and 2) The open input bias voltage for the input is known or measured within the same test sequence.

Under the above assumptions R_{IN} can be correlated to the input current measured. The expression

$$R_{IN} = \frac{(V_{ICM} - V_{IN}) (R_T)}{(I_{IN}) (R_{25})}$$

where V_{ICM} is the open input bias voltage of the Line Receiver. When applying this correlation to the 26LS32 die, the following criteria have been set.

- 1) V_{ICM} and I_{IN} are the values screened at wafer sort.
- 2) Temperature coefficients are for 800 ohm/square which gives 0.96 at 0°C and 0.93 at -55°C.

When setting limits, characterized values for V_{ICM} have been used instead of the test programmed limit value. $R_{IN} (dif)$ is $R_{IN} (dif) = 2 R_{IN}$.

For the Am26LS32/32B/33/34

$$R_{IN} \text{ Min.} = \frac{(2.56 - -15) 0.96}{I_{IN} (\text{Max.})} = 16.8/I_{IN} (\text{Max.}) \text{ Comm.,}$$

and

$$R_{IN} \text{ Min.} = 16.3/I_{IN} (\text{Max.}) \text{ Mil.}$$

Worst Case Measurement for Input Current

Two considerations have been used to determine the test condition for input current of the data path for the Am26LS32 Line Receiver.

- 1) Input current is tested on the 26LS32 with the pin under test at one end of the range (+15 V for example) and the untested pin at the opposite extreme of the input range under test. If both pins were at the same test voltage the internal bias generator would have a lower output voltage for tests at -15 V V_{IN} and a higher output voltage at +15 V V_{IN} . This would produce test currents less than maximum.
- 2) For the 26LS32, breakdown of the differential inputs is the primary failure to the data sheet specification. Hence, both breakdown voltage and input current are tested during the input current tests.

ATTACHMENT II

Test Documentation For Am26LS32/32B/34 V_{TH}

Input threshold (V_{TH}) for the Am26LS32/32B/34 is described by the equation,

$$V_{TH} = (N+1) (1+R1/R) K^*T/Q ((1+Rh/(M(Rc+Rh))) / (1-Rh/(M(Rc+Rh))))$$

Where $N+1$ is the attenuator ratio, $R1/R$ is the attenuator ratio mismatch, M is the ratio of the input stage current to hysteresis stage current, and Rh and Rc are input stage loads. For Am26LS32 – 34 devices which pass function tests, V_{OH} and V_{OL} tests, thresholds for all inputs within the operating range of the circuit.

The Test system is unable to force input thresholds within the accuracy required for the Am26LS32 – 34 specifications. Figure 1 plots the expected values for V_{TH} , the worst case values at 25°C and 155°C. Also shown are the test values for V_{TH} at the –1.5 V input (V_{IN}). In addition, the test voltage at –7 V V_{IN} is shown.

For the figure it is seen that the worst case value for the test limit shown would be ± 165 mV, where ± 102 mV is expected for process parameters and the equation for V_{TH} . Further the 25 mV negative guardband used for –7 V testing is less than half the machine uncertainty of 60 mV.

When QA testing for Am26LS32/32B/34 is done, thresholds are screened for V_{CM} other than –1.5 V. These additional tests are considered functional tests only, and the precision threshold tests which insure compliance with data sheet limits are those tests performed where the inputs are tested near –1.5 V.

The actual threshold tests are done as a sequence where a setup is performed which preconditions the DUT to a logic one state, then the threshold correlation for a logic zero is tested followed by a threshold correlation for logic one to complete the sequence. The limit values for the setup (V_t SET), logic zero test (V_t “–”), and logic one test (V_t “+”) are listed under V_{TH} for supply value of 5.0 V.

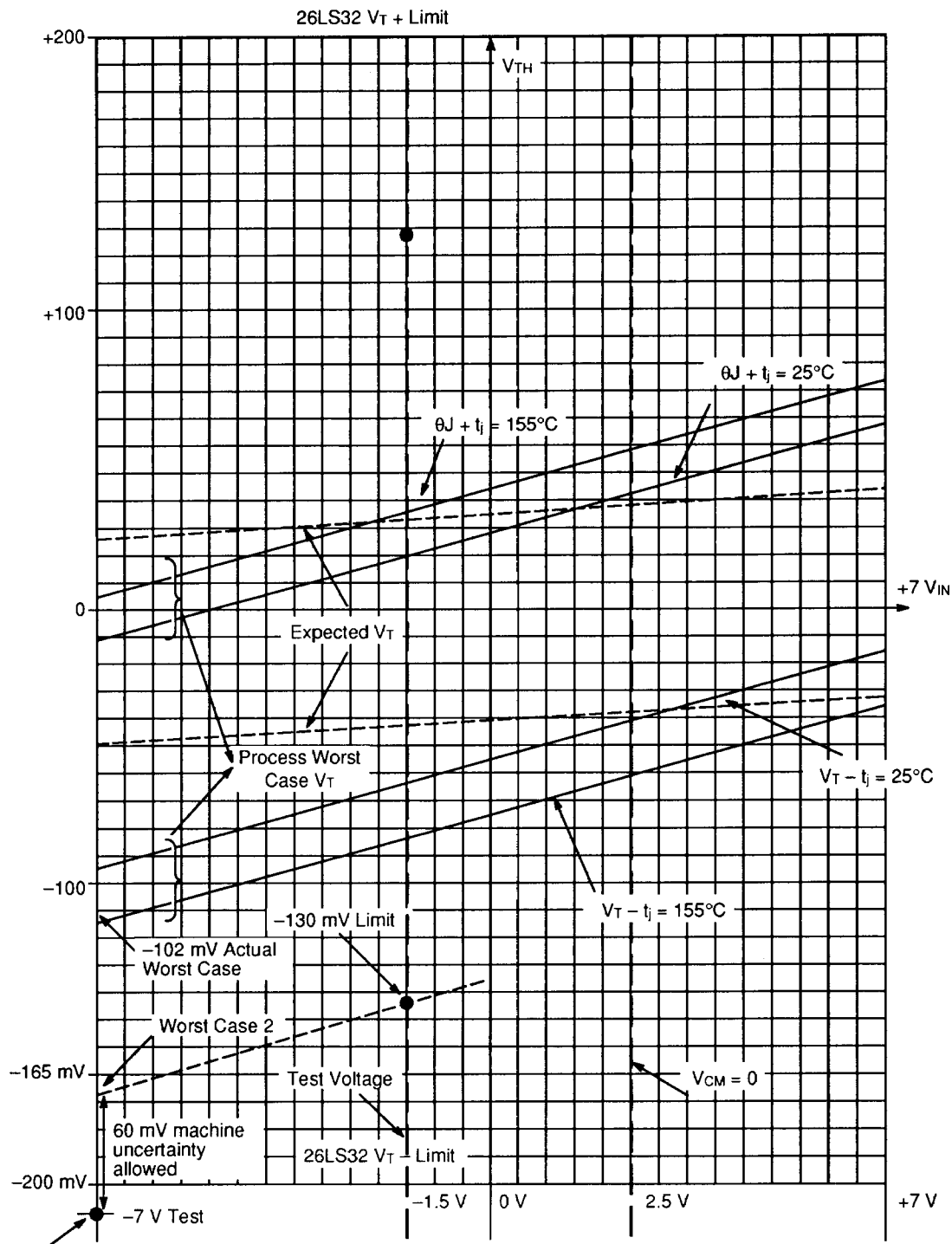


Figure 1. 26LS32 Input Threshold V_T vs. Input Voltage V_{IN}